

Accurate Thermal Analysis Considering Nonlinear Thermal Conductivity

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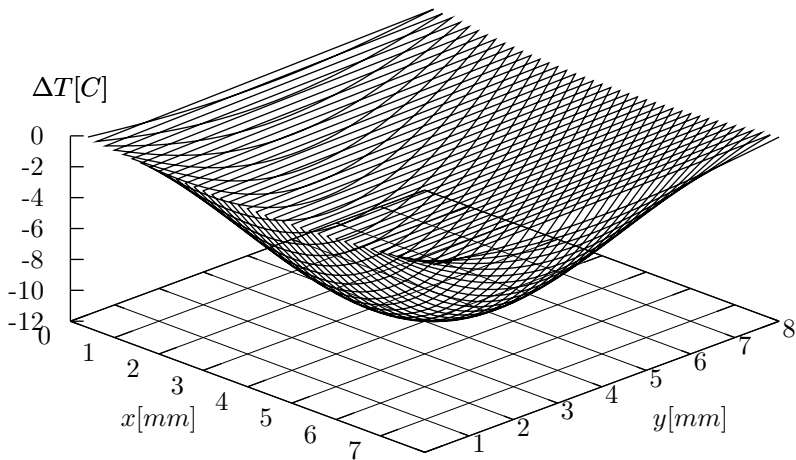


Introduction & Motivation

- Why thermal analysis?
 - Temperature affects performance
 - Temperature and power are tightly coupled
 - Reliability issues
- Is *Electrothermal* analysis any different in *digital* domain compared to *analog* domain?
 - Essentially involves solving $A(x)x = b$
 - The **size** of A is the biggest challenge



Difference in temperature on ignoring thermal conductivity



Heat conduction equation

- A partial differential equation of the form,

$$\rho C_p \frac{\partial T(x, y, z, t)}{\partial t} = \kappa(T(x, y, z, t)) \nabla^2 T(x, y, z, t) + h(x, y, z, t)$$

where

- $\kappa(T(x, y, z, t))$ is the thermal conductivity
 - $h(x, y, z, t)$ is a heat source at (x, y, z, t) .
 - ρC_p is the heat capacity
- Since we are interested in *steady state*, the above equation reduces to,

$$\kappa(T(x, y, z)) \nabla^2 T(x, y, z) + h(x, y, z) = 0$$



Finite difference in 1-dimension

- Let us consider the problem in one dimension and in one layer (silicon) to simplify things The heat conduction equation reduces to,

$$\kappa_{\text{si}}(T) \frac{\partial^2 T(x)}{\partial x^2} + h(x) = 0$$

- Applying finite difference to the heat conduction equation,

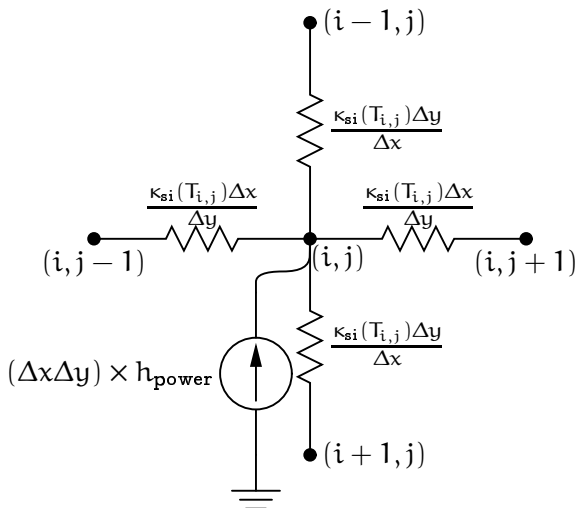
$$\kappa_{\text{si}}(T_i) \left(\frac{\left(\frac{T_{i+1} - T_i}{\Delta x} \right) - \left(\frac{T_i - T_{i-1}}{\Delta x} \right)}{\Delta x} \right) + h(x) = 0$$

$$\frac{\kappa_{\text{si}}(T_i)}{(\Delta x)^2} (2T_i - T_{i-1} - T_{i+1}) = h(x)$$

- Can be written in matrix form as $\mathbf{K}(\mathbf{T})\mathbf{T} = \mathbf{h}$.



Electrical Interpretation in 2-dimension

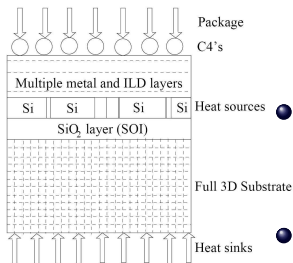


Size of the Matrix

- In literature, $\mathbf{K}(\mathbf{T})\mathbf{T} = \mathbf{h}$ is solved as $\mathbf{K}\mathbf{T} = \mathbf{h}$ [Cheng 1998, Wang 2003]
 - Linear system of equations
 - Still difficult to solve due to sheer size
 - Consider a $8000\mu\text{m} \times 8000\mu\text{m}$ chip with grid size of $\Delta x \times \Delta y = 10\mu\text{m} \times 10\mu\text{m}$
 - The size of the matrix \mathbf{K} is $\mathbb{R}^{640,000 \times 640,000}$
 - Fortunately, the matrix is sparse
- To get an accurate solution need to solve the nonlinear system of equations $\mathbf{K}(\mathbf{T})\mathbf{T} = \mathbf{h}$
 - Very hard since there are no black box methods to solve a nonlinear system of equations



Steady state thermal circuit

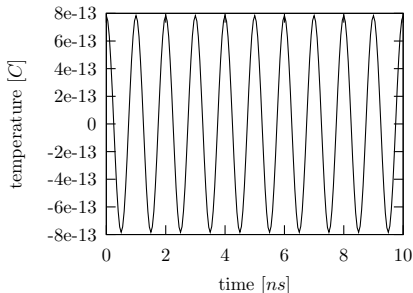


- We study if steady state (SS) heat sources can be modeled as a DC source having the RMS value of SS
- The steady state problem is studied in z direction, assume uniformity in x, y directions
- Picture of chip layers from [Su, ISLPED 2003]

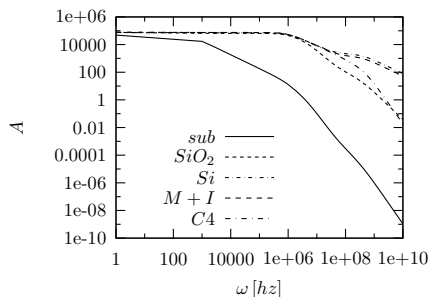


Steady State Response

- The RMS analysis is done by setting the DC sources to zero and setting the ac source to the RMS value
- The temperature rise at the substrate calculated using the RMS values for the ac sources is 2.65°C
- The steady state response turns out to be zero!
- Thus the approximation is good



Time constant of the substrate



- The thermal time constant is dominated by the substrate which is around KHz and the operating frequency is GHz



Nonlinear thermal conductivity

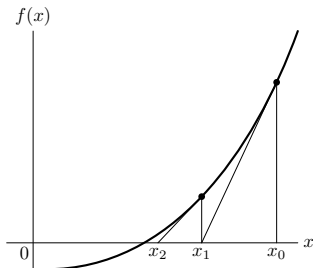
- Thermal conductivity is a nonlinear function of temperature
 - There is a 22 % change in thermal conductivity of Silicon over the range of $[27, 80]^{\circ}\text{C}$
 - Thermal gradients calculated assuming constant thermal conductivity is not very accurate
- Challenge is designing efficient algorithms to solve system of m nonlinear equations simultaneously



Algorithms to solve nonlinear equations

● Newton-Raphson

$$\mathbf{x}^{(k)} = \mathbf{x}^{(k-1)} - [\mathbf{J}(\mathbf{x}^{(k-1)})]^{-1} \mathbf{f}(\mathbf{x}^{(k-1)})$$

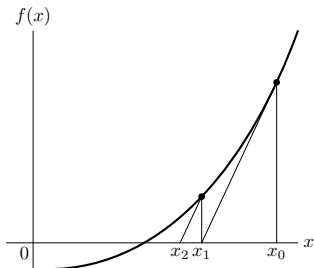


- Simple and fast convergence
- Need to factorize the Jacobian matrix during every iteration

Algorithms to solve nonlinear equations

- **Constant Jacobian**

$$\mathbf{x}^{(k)} = \mathbf{x}^{(k-1)} - [\mathbf{J}(\mathbf{x}^{(0)})]^{-1} \mathbf{f}(\mathbf{x}^{(k-1)})$$

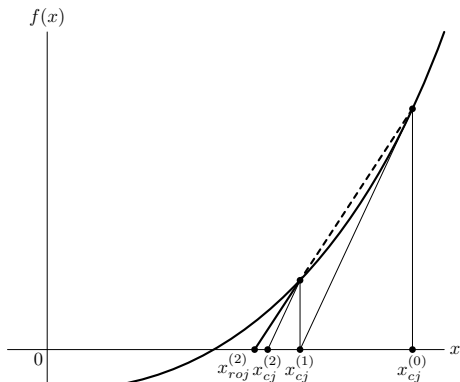


- Only *one* factorization
- But slow convergence



Sketch of Proposed Algorithm

- Accelerate **Constant Jacobian**



Proposed Algorithm

Input: $\mathbf{F}(\mathbf{x}) \triangleq \mathbf{A}(\mathbf{x})\mathbf{x} - \mathbf{b}$: m nonlinear equations in m unknowns

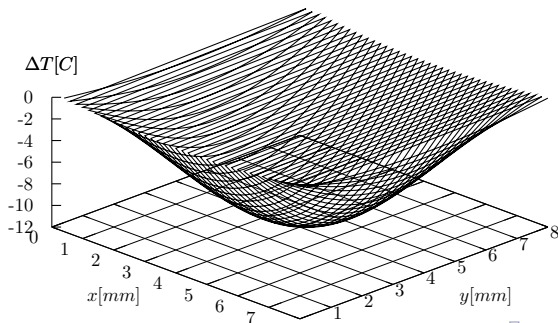
Input: p , the number of partitions $\mathbf{A}(\mathbf{x})$ is divided into

- 1: $k \leftarrow 0$
- 2: **repeat**
- 3: // Use reduced Jacobian every q th iteration
- 4: // after the first $k = p + 1$ iterations
- 5: **if** $((k > p) \text{ and } !(k \% q))$ **then**
- 6: Use reduced Jacobian
- 7: **else**
- 8: Use constant Jacobian
- 9: **end if**
- 10: $k \leftarrow k + 1$
- 11: **until** Convergence



Difference in temperature on ignoring thermal conductivity

- Difference in temperature in a silicon layer between having a constant thermal conductivity (27°C) and incorporating nonlinearity
- The chip dimension is $8\text{mm} \times 8\text{mm}$ and it dissipates 100 W uniformly



Conclusion

- RMS response is an upper bound on the steady state response when thermal analysis is done at transistor level
- Accurate thermal analysis needs to consider nonlinear thermal conductivity
- An efficient algorithm to solve the system of nonlinear equations has been proposed

